Quad 2-Input Multiplexer with 3-State Outputs

The LSTTL/MSI SN74LS257B and the SN74LS258B are Quad 2-Input Multiplexers with 3-state outputs. Four bits of data from two sources can be selected using a Common Data Select input. The four outputs present the selected data in true (non-inverted) form. The outputs may be switched to a high impedance state with a HIGH on the common Output Enable ($E_{\rm O}$) Input, allowing the outputs to interface directly with bus oriented systems. It is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Schottky Process For High Speed
- Multiplexer Expansion By Tying Outputs Together
- Non-Inverting 3-State Outputs
- Input Clamp Diodes Limit High Speed Termination Effects
- Special Circuitry Ensures Glitch Free Multiplexing
- ESD > 3500 Volts

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-2.6	mA
I _{OL}	Output Current – Low			24	mA



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LOW POWER SCHOTTKY



N SUFFIX CASE 648

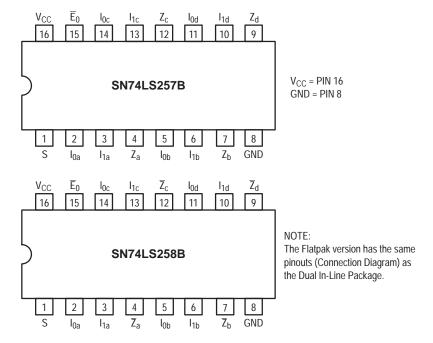


SOIC D SUFFIX CASE 751B

ORDERING INFORMATION

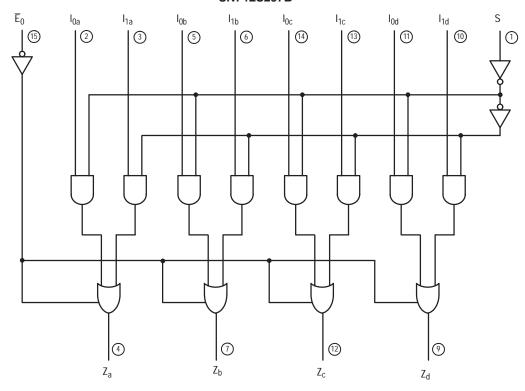
Device	Package	Shipping	
SN74LS257BN	16 Pin DIP	2000 Units/Box	
SN74LS257BD	16 Pin	2500/Tape & Reel	
SN74LS258BN	16 Pin DIP	2000 Units/Box	
SN74LS258BD	16 Pin	2500/Tape & Reel	

CONNECTION DIAGRAM DIP (TOP VIEW)

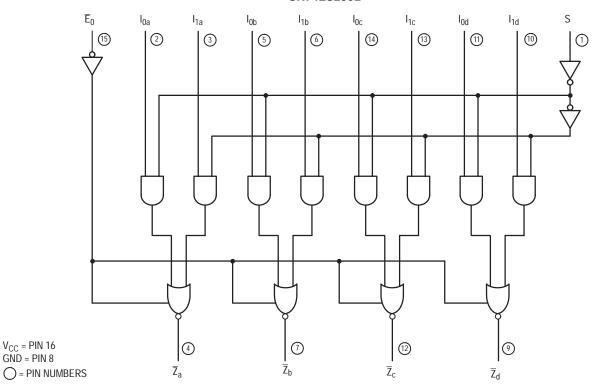


LOGIC DIAGRAMS

SN74LS257B



SN74LS258B



V_{CC} = PIN 16 GND = PIN 8

FUNCTIONAL DESCRIPTION

The LS257B and LS258B are Quad 2-Input Multiplexers with 3-state outputs. They select four bits of data from two sources each under control of a Common Data Select Input. When the Select Input is LOW, the $\rm I_0$ inputs are selected and when Select is HIGH, the $\rm I_1$ inputs are selected. The data on the selected inputs appears at the outputs in true (non-inverted) form for the LS257B and in the inverted form for the LS258B.

The LS257B and LS258B are the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select Input. The logic equations for the outputs are shown below:

$$\begin{array}{l} \textbf{LS258B} \\ \overline{Z}_a = \overline{E}_0 \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S}) \ \overline{Z}_b = \overline{E}_0 \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S}) \\ \overline{Z}_c = \overline{E}_0 \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S}) \ \overline{Z}_d = \overline{E}_0 \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S}) \end{array}$$

When the Output Enable Input (\overline{E}_0) is HIGH, the outputs

are forced to a high impedance "off" state. If the outputs are

tied together, all but one device must be in the high

impedance state to avoid high currents that would exceed the

maximum ratings. Designers should ensure that Output

Enable signals to 3-state devices whose outputs are tied

together are designed so there is no overlap.

LS257F

$$\begin{array}{l} Z_a = \overline{E}_0 \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S}) \ Z_b = \overline{E}_0 \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S}) \\ \overline{Z}_c = \overline{E}_0 \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S}) \ \overline{Z}_d = \overline{E}_0 \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S}) \end{array}$$

TRUTH TABLE

OUTPUT ENABLE	SELECT INPUT	DATA INPUTS				OUTPUTS LS257B	OUTPUTS LS258B
Ēo	S	I ₀	I ₁	Z	Z		
Н	Х	Х	Χ	(Z)	(Z)		
L	Н	Х	L	L	Н		
L	Н	Х	Н	Н	L		
L	L	L	Χ	L	Н		
L	L	Н	Χ	Н	L		

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

⁽Z) = High Impedance (off)

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter		Min	Тур	Max	Unit	Test Conditions	
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V _{IK}	Input Clamp Diode Voltage			-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} =$	–18 mA
V _{OH}	Output HIGH Voltage		2.4	3.1		V	$V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH}$ or V_{IL} per Truth Table	
V	Output LOW/Voltage			0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$
V _{OL}	Output LOW Voltage			0.35	0.5	V	$I_{OL} = 24 \text{ mA}$ $V_{IN} = V_{IL} \text{ or } V_{IH}$ per Truth Table	
l _{OZH}	Output Off Current — HIGH	1			20	μА	V _{CC} = MAX, V _{OUT} = 2.7 V	
I _{OZL}	Output Off Current — LOW	1			-20	μΑ	V _{CC} = MAX, V _{OUT} = 0.4 V	
I _{IH}	Input HIGH Current Other Inputs S Inputs				20 40	μА	$V_{CC} = MAX, V_{IN} = 2.7 \text{ V}$ $V_{CC} = MAX, V_{IN} = 7.0 \text{ V}$	
	Other Inputs S Inputs				0.1 0.2	mA		
I _{IL}	Input LOW Current All Inputs				-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS}	Short Circuit Current (Note	1)	-30		-130	mA	V _{CC} = MAX	
	Power Supply Current Total, Output HIGH	LS257B LS258B			10 9.0	· .		
I _{CC}	Total, Output LOW	LS257B LS258B			16 14	mA	V _{CC} = MAX	
	Total, Output 3-State	LS257B LS258B			19 16	mA		

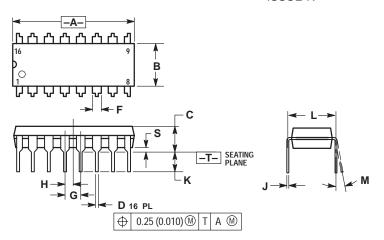
Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$) See SN74LS251 for Waveforms

		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions	
t _{PLH} t _{PHL}	Propagation Delay, Data to Output		10 12	13 15	ns	Figures 1 & 2	C ₁ = 45 pF
t _{PLH} t _{PHL}	Propagation Delay, Select to Output		14 14	21 21	ns	Figures 1 & 2	C _L = 45 pF
t _{PZH}	Output Enable Time to HIGH Level		20	25	ns	Figures 4 & 5	C _L = 45 pF
t _{PZL}	Output Enable Time to LOW Level		20	25	ns	Figures 3 & 5	$R_L = 667 \Omega$
t _{PLZ}	Output Disable Time to LOW Level		16	25	ns	Figures 3 & 5	C _L = 5.0 pF
t _{PHZ}	Output Disable Time from HIGH Level		18	25	ns	Figures 4 & 5	$R_L = 667 \Omega$

PACKAGE DIMENSIONS

N SUFFIX PLASTIC PACKAGE CASE 648-08 ISSUE R

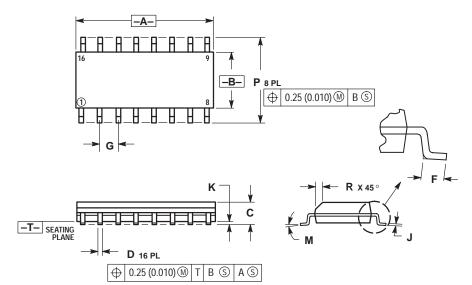


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10 °	0°	10 °	
S	0.020	0.040	0.51	1.01	

PACKAGE DIMENSIONS

D SUFFIX PLASTIC SOIC PACKAGE CASE 751B-05 ISSUE J



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES		
DIM	MIN MAX		MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0 °	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

SN741 S257B SN741 S258B

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